

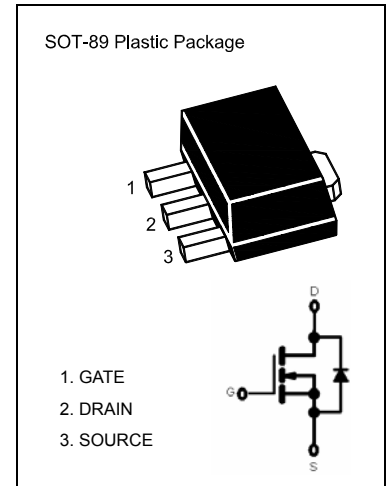
SOT-89 Plastic-Encapsulate MOSFETS

P-Channel Enhancement Mode Field Effect Transistor

FEATURE

- High dense cell design for extremely low $R_{DS(ON)}$.
- Exceptional on-resistance and maximum DC current capability

MARKING: 3401



Maximum ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	-4.2	A
Power Dissipation	P_D	350	mW
Thermal Resistance from Junction to Ambient (t<5s)	$R_{\theta JA}$	357	$^{\circ}\text{C}/\text{W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~+150	$^{\circ}\text{C}$

Electrical characteristics (T_a=25°C unless otherwise noted)

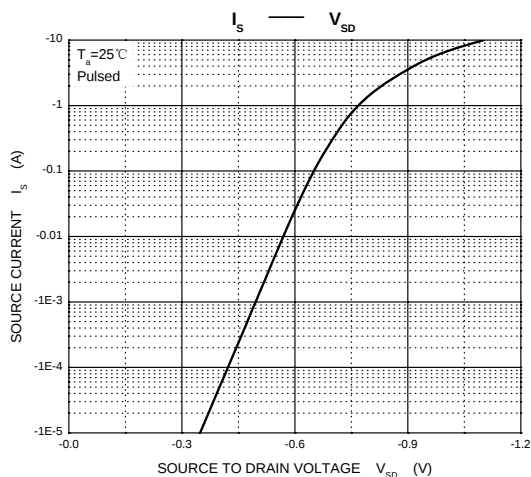
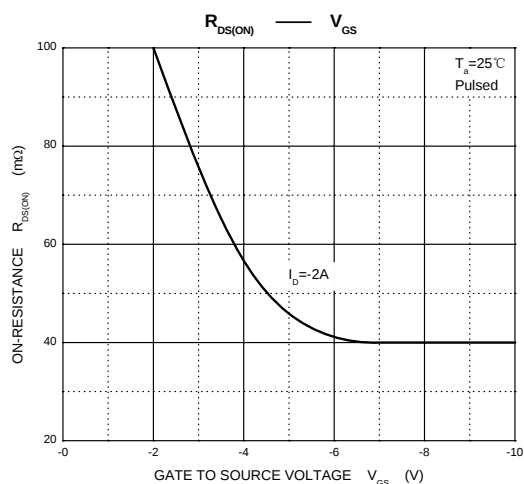
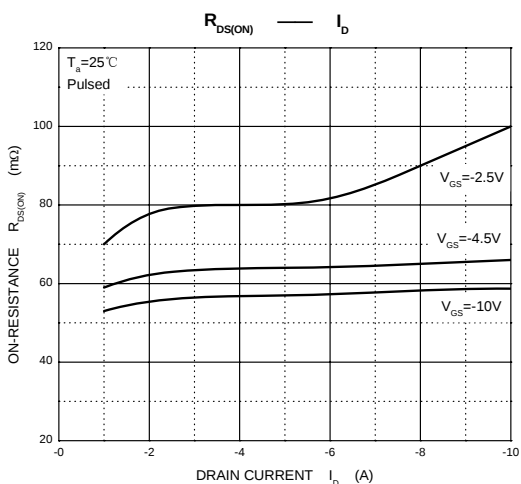
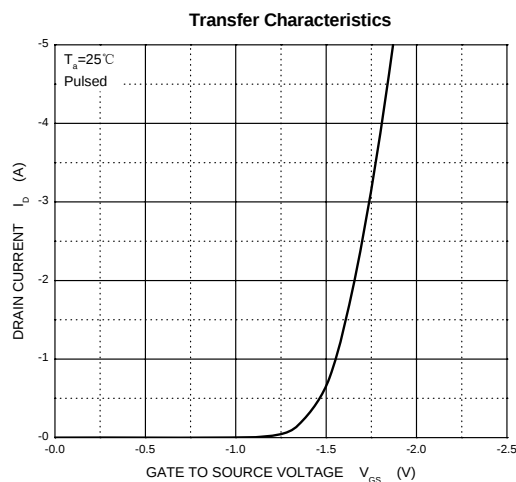
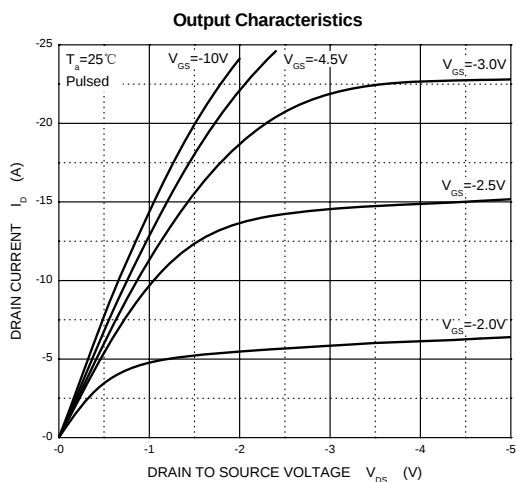
Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	-30			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-24V,V _{GS} = 0V			-1	μA
Gate-source leakage current	I _{GSS}	V _{GS} =±12V, V _{DS} = 0V			±100	nA
On characteristics						
Drain-source on-resistance (note 1)	R _{DS(on)}	V _{GS} =-10V, I _D =-4.2A			65	mΩ
		V _{GS} =-4.5V, I _D =-4A			75	mΩ
		V _{GS} =-2.5V,I _D =-1A			90	mΩ
Forward tranconductance (note 1)	g _{FS}	V _{DS} =-5V, I _D =-5A	7			S
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.7		-1.3	V
Dynamic characteristics (note 2)						
Input capacitance	C _{iss}	V _{DS} =-15V,V _{GS} =0V,f =1MHz		954		pF
Output capacitance	C _{oss}			115		pF
Reverse transfer capacitance	C _{rss}			77		pF
Switching characteristics (note 2)						
Turn-on delay time	t _{d(on)}	V _{GS} =-10V,V _{DS} =-15V, R _L =3.6Ω,R _{GEN} =6Ω			6.3	ns
Turn-on rise time	t _r				3.2	ns
Turn-off delay time	t _{d(off)}				38.2	ns
Turn-off fall Time	t _f				12	ns
Drain-source diode characteristics and maximum ratings						
Diode forward voltage (note 1)	V _{SD}	I _S =-1A,V _{GS} =0V			-1	V

Note :

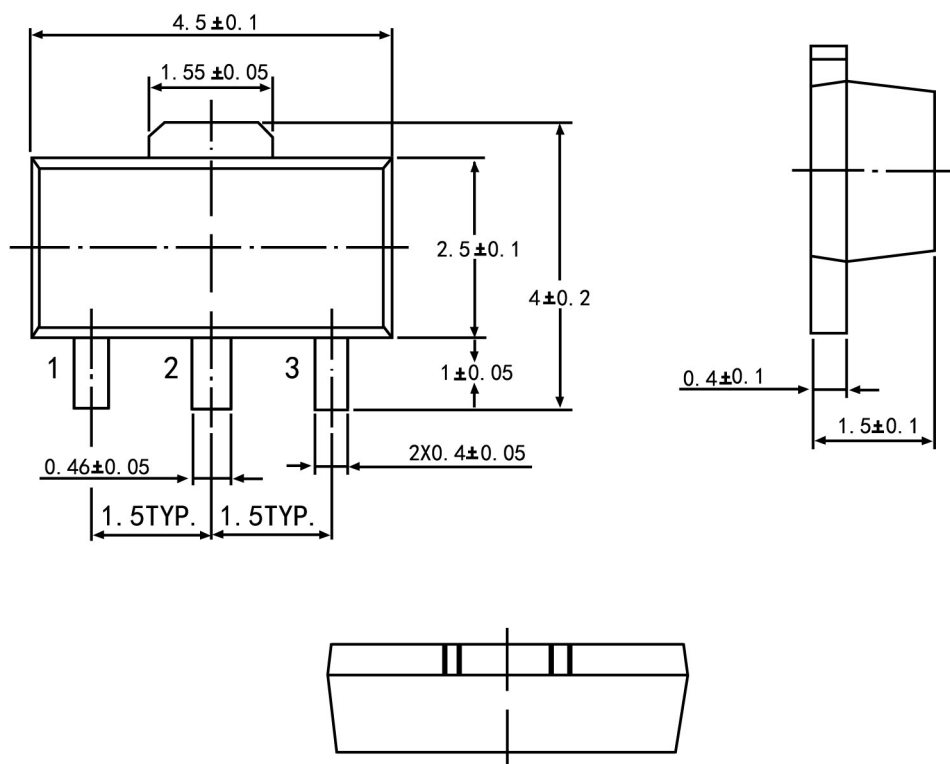
1. Pulse Test : Pulse width ≤ 300μs, duty cycle ≤ 2%.
2. These parameters have no way to verify.

Typical Characteristics

BC3401U



SOT-89 PACKAGE OUTLINE



Symbol	Dimension in Millimeters	
	Min	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.44
D	4.40	4.60
D1	1.62	1.83
E	2.29	2.60
e	1.50 Typ	
H	3.94	4.25
H1	2.63	2.93
L	0.89	1.20
All Dimensions In mm		